## NSN 5962-01-521-1536

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1.0 watts  Storage Tempurature Range: -65.0/+150.0 degrees celsius  End Application: Eurofighter 2000 Inclosure Material: Plastic Inclosure Configuration: Dual-in-line Output Logic Form:
-65.0/+150.0 degrees celsius  End Application: Eurofighter 2000 Inclosure Material: Plastic Inclosure Configuration: Dual-in-line Output Logic Form:
End Application: Eurofighter 2000 Inclosure Material: Plastic Inclosure Configuration: Dual-in-line Output Logic Form:
Eurofighter 2000 Inclosure Material: Plastic Inclosure Configuration: Dual-in-line Output Logic Form:
Inclosure Material: Plastic Inclosure Configuration: Dual-in-line Output Logic Form:
Plastic Inclosure Configuration: Dual-in-line Output Logic Form:
Inclosure Configuration:  Dual-in-line  Output Logic Form:
Dual-in-line Output Logic Form:
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Product Name:
Microcircuit, memory, digital
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts output logic low
Memory Device Type:
Ram
Hybrid Technology Type:
Monolithic
Memory Capacity:
32kx8
Terminal Type And Quantity:
32 leadless
Specification Data:
5962-88552 government standard
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0